PBSS5160T-Q

60 V, 1 A PNP low VCEsat transistor

4 October 2023

Product data sheet

1. General description

PNP low VCEsat transistor in a small SOT23 (TO-236AB) Surface-Mounted Device (SMD) plastic package.

NPN complement: PBSS4160T-Q

2. Features and benefits

- · Low collector-emitter saturation voltage VCEsat
- High collector current capability IC and ICM
- · High efficiency due to less heat generation
- Reduces Printed-Circuit Board (PCB) area required
- Cost-effective replacement for medium power transistors BCP52 and BCX52
- Qualified according to AEC-Q101 and recommended for use in automotive applications

3. Applications

- Major application segments:
 - Automotive
 - · Telecom infrastructure
 - Industrial
- Power management:
 - · JDC-to-DC conversion
 - Supply line switching
- Peripheral driver:
 - Driver in low supply voltage applications (e.g. lamps and LEDs)
 - Inductive load drivers (e.g. relays, buzzers and motors)

4. Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
V _{CEO}	collector-emitter voltage	open base		-	-	-60	V
I _C	collector current		[1]	-	-	-1	Α
I _{CM}	peak collector current	limited by T _{j(max)} ; t _p = 1 ms		-	-	-2	А
R _{CEsat}	collector-emitter saturation resistance	I_C = -1 A; I_B = -100 mA; pulsed; $t_p \le$ 300 μs; $\delta \le$ 0.02; T_{amb} = 25 °C		-	220	330	mΩ

[1] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².



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5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	В	base	3	
2	Е	emitter		C
3	С	collector		В—
			1 2	E sym132
			SOT23	

6. Ordering information

Table 3. Ordering information

Type number	Package		
	Name	Description	Version
PBSS5160T-Q	SOT23	plastic, surface-mounted package; 3 terminals; 1.9 mm pitch; 2.9 mm x 1.3 mm x 1 mm body	SOT23

7. Marking

Table 4. Marking codes

Type number	Marking code[1]
PBSS5160T-Q	%U6

[1] % = placeholder for manufacturing site code

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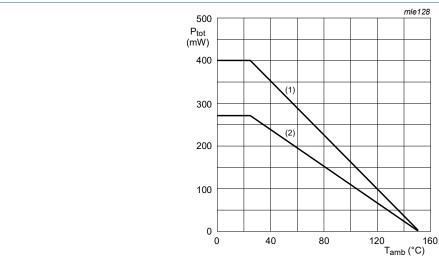
8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CBO}	collector-base voltage	open emitter		-	-80	V
V_{CEO}	collector-emitter voltage	open base		-	-60	V
V _{EBO}	emitter-base voltage	open collector		-	-5	V
I _C	collector current		[1]	-	-0.9	А
			[2]	-	-1	А
I _{CM}	peak collector current	limited by T _{j(max)} ; t _p = 1 ms		-	-2	А
I _B	base current			-	-300	mA
I _{BM}	peak base current	tp ≤ 300 μs; δ ≤ 0.02; pulsed		-	-1	А
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[1]	-	270	mW
			[2]	-	400	mW
			[1] [3]	-	1.25	W
Tj	junction temperature			-	150	°C
T _{amb}	ambient temperature			-65	150	°C
T _{stg}	storage temperature			-65	150	°C

- [1] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm².
- [3] Operated under pulse conditions: duty cycle $\delta \le 20$ %, pulse width $t_p \le 10$ ms.



- (1) FR4 PCB mounting pad for collector 1 cm²
- (2) FR4 PCB, standard footprint

Fig. 1. Power derating curves

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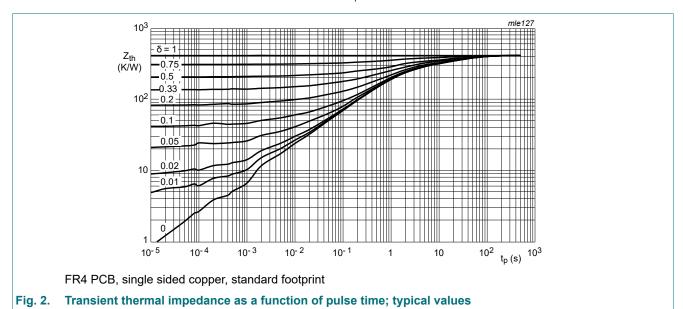
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9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
$R_{th(j-a)}$	thermal resistance from	in free air	[1]	-	-	465	K/W
junction to ambient		[2]	-	-	312	K/W	
			[1] [3]	-	-	100	K/W

- Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for collector 1 cm 2 . Operated under pulse conditions: duty cycle $\delta \le 20$ %, pulse width $t_p \le 10$ ms.
- [3]

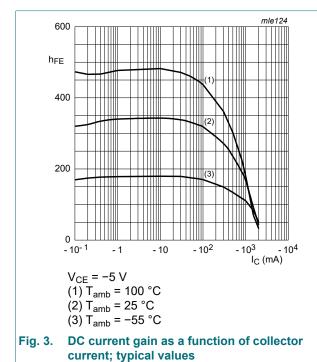


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10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off	V _{CB} = -60 V; I _E = 0 A; T _{amb} = 25 °C	-	-	-100	nA
	current	V _{CB} = -60 V; I _E = 0 A; T _j = 150 °C	-	-	-50	μΑ
I _{EBO}	emitter-base cut-off current	$V_{EB} = -5 \text{ V}; I_{C} = 0 \text{ A}; T_{amb} = 25 \text{ °C}$	-	-	-100	nA
I _{CES}	collector-emitter cut-off current	V _{CE} = -60 V; V _{BE} = 0 V; T _{amb} = 25 °C	-	-	-100	nA
h _{FE}	DC current gain	V _{CE} = -5 V; I _C = -1 mA; T _{amb} = 25 °C	200	350	-	
		V_{CE} = -5 V; I_{C} = -500 mA; pulsed; $t_{p} \le$ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	150	250	-	
		V_{CE} = -5 V; I_{C} = -1 A; pulsed; t_{p} ≤ 300 μs; δ ≤ 0.02; T_{amb} = 25 °C	100	160	-	
V _{CEsat}	collector-emitter saturation voltage	I_C = -100 mA; I_B = -1 mA; T_{amb} = 25 °C	-	-110	-160	mV
		I _C = -500 mA; I _B = -50 mA; T _{amb} = 25 °C	-	-120	-175	mV
		I_C = -1 A; I_B = -100 mA; pulsed; $t_p \le$	-	-220	-330	mV
R _{CEsat}	collector-emitter saturation resistance	300 μs; δ ≤ 0.02; T _{amb} = 25 °C	-	220	330	mΩ
V _{BEsat}	base-emitter saturation voltage	$I_C = -1 \text{ A}; I_B = -50 \text{ mA}; T_{amb} = 25 ^{\circ}\text{C}$	-	-0.95	-1.1	V
V_{BEon}	base-emitter turn-on voltage	V _{CE} = -5 V; I _C = -1 A; T _{amb} = 25 °C	-	-0.82	-0.9	V
f _T	transition frequency	V_{CE} = -10 V; I_{C} = -50 mA; f = 100 MHz; T_{amb} = 25 °C	150	220	-	MHz
C _c	collector capacitance	$V_{CB} = -10 \text{ V}; I_E = 0 \text{ A}; i_e = 0 \text{ A};$ f = 1 MHz; $T_{amb} = 25 \text{ °C}$	-	9	15	pF



mle125 I_B (mA) = - 20 - 24 - 28 - 32 lc (A) - 1.6 16 12 - 1.2 8 -- 0.8 -4 -5 V_{CE} (V) - 1 - 2 - 3 T_{amb} = 25 °C

Fig. 4. Collector current as a function of collectoremitter voltage; typical values

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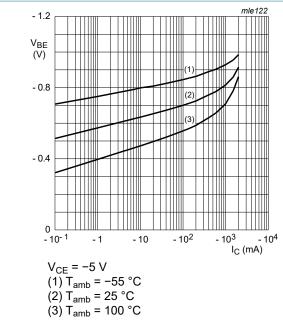
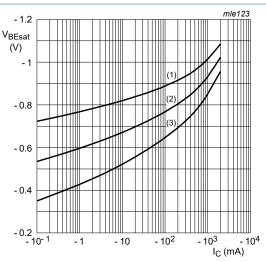


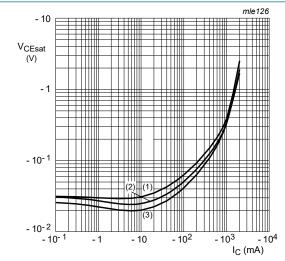
Fig. 5. Base-emitter voltage as a function of collector current; typical values



 $I_{\rm C}/I_{\rm B}=20$

(1) $T_{amb} = -55 \,^{\circ}\text{C}$ (2) $T_{amb} = 25 \,^{\circ}\text{C}$ (3) $T_{amb} = 100 \,^{\circ}\text{C}$

Fig. 6. Base-emitter saturation voltage as a function of collector current; typical values



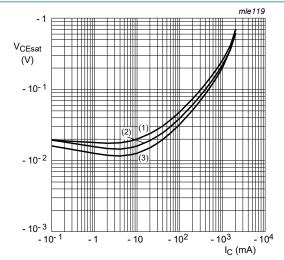
 $I_C/I_B = 20$

(1) T_{amb} = 100 °C

(2) T_{amb} = 25 °C

(3) $T_{amb} = -55 \,^{\circ}C$

Fig. 7. Collector-emitter saturation voltage as a function of collector current; typical values



 $I_C/I_B = 10$

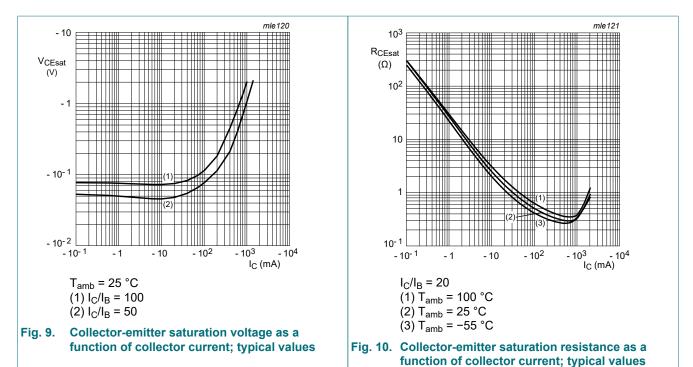
(1) $T_{amb} = 100 \, ^{\circ}C$

(2) $T_{amb} = 25 \, ^{\circ}C$

(3) $T_{amb} = -55$ °C

Fig. 8. Collector-emitter saturation voltage as a function of collector current; typical values

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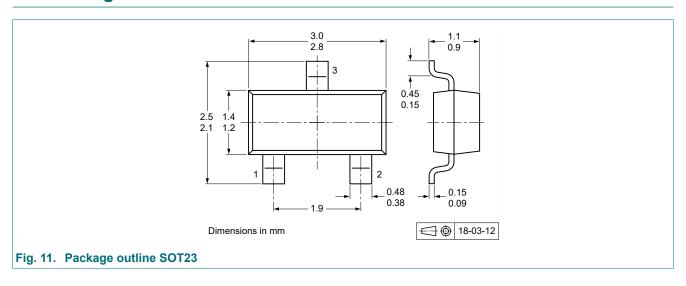


11. Test information

Quality information

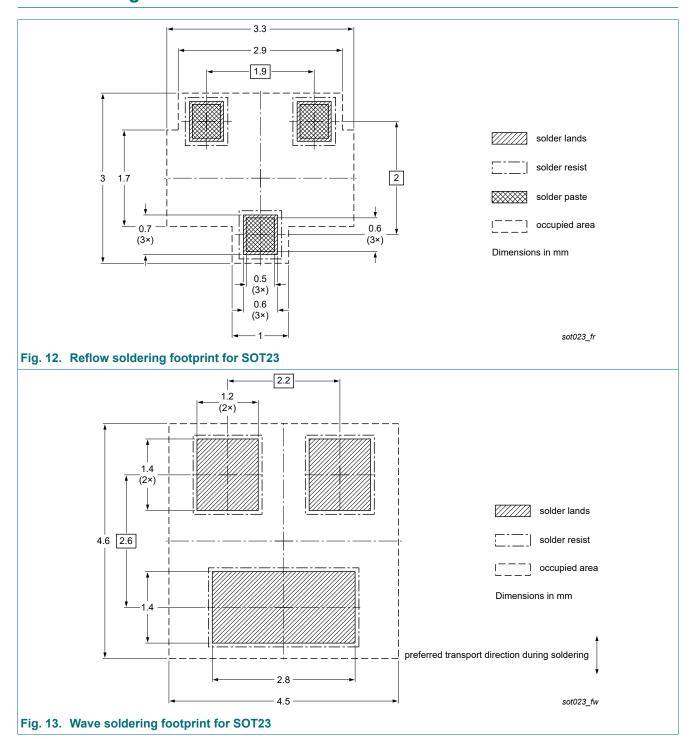
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard *Q101 - Stress test qualification for discrete semiconductors*, and is suitable for use in automotive applications.

12. Package outline



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13. Soldering



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14. Revision history

Table 8. Revision history

Data sheet ID	Release date	Data sheet status	Change notice	Supersedes
PBSS5160T-Q v.1	20231004	Product data sheet	-	-

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15. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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